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Features

- Superscalar (3 Instructions per Clock Peak)
- Dual 16 KB Caches
- Selectable Bus Clock
- 32-bit Compatibility PowerPC Implementation
- On-chip Debug Support
- Nap, Doze and Sleep Power Saving Modes
- Device Offered in Cerquad, CBGA 255, HiTCE CBGA 255 and CI-CGA 255

Features Specific to CBGA 255, HiTCE CBGA 255 and CI-CGA 255

- 7.4 SPECint95, 6.1 SPECfp95 at 300 MHz (Estimated)
- P_D Typically = 3.5W (266 MHz), Full Operating Conditions
- Branch Folding
- 64-bit Data Bus (32-bit Data Bus Option)
- 4-Gbytes Direct Addressing Range
- Pipelined Single/Double Precision Float Unit
- IEEE 754 Compatible FPU
- IEEE P 1149-1 Test Mode (JTAG/C0P)
- f_{INT} Max = 300 MHz
- f_{BUS} Max = 75 MHz
- Compatible CMOS Input/TTL Output

Features Specific to Cerquad

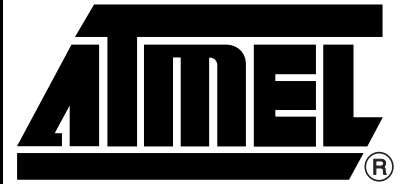
- 5.6 SPECint95, 4 SPECfp95 and 200 MHz (Estimated)
- P_D Typically = 2.5W (200 MHz), Full Operating Conditions

1. Description

The PID7t-603e implementation of the PowerPC 603e (renamed after the 603R) is a low-power implementation of the Reduced Instruction Set Computer (RISC) microprocessor PowerPC family. The 603R is pin-to-pin compatible with the PowerPC 603e and 603P in a Cerquad package. The 603R implements 32-bit effective addresses, integer data types of 8, 16 and 32 bits, and floating-point data types of 32 and 64 bits.

The 603R is a low-power 2.5/3.3V design and provides four software controllable power-saving modes. This device is a superscalar processor capable of issuing and retiring as many as three instructions per clock. Instructions can be executed in any order for increased performance, but, the 603R makes completion appear sequential. It integrates five execution units and is able to execute five instructions in parallel.

The 603R provides independent on-chip, 16-Kbyte, four-way set-associative, physically addressed caches for instructions and data, as well as on-chip instructions, and data Memory Management Units (MMUs). The MMUs contain 64-entry, two-way set-associative, data and instruction translation look aside buffers that provide support for demand-paged virtual memory address translation and variable-sized block translation. The 603R has a selectable 32- or 64-bit data bus and a 32-bit address bus. The interface protocol allows multiple masters to compete for system resources through a central external arbiter. The device supports single-beat and burst data transfers for memory accesses, and supports memory-mapped I/Os.



PowerPC® 603e
RISC
Microprocessor
Family
PID7t-603e

TSPC603R

Rev. 5410B-HIREL-09/05

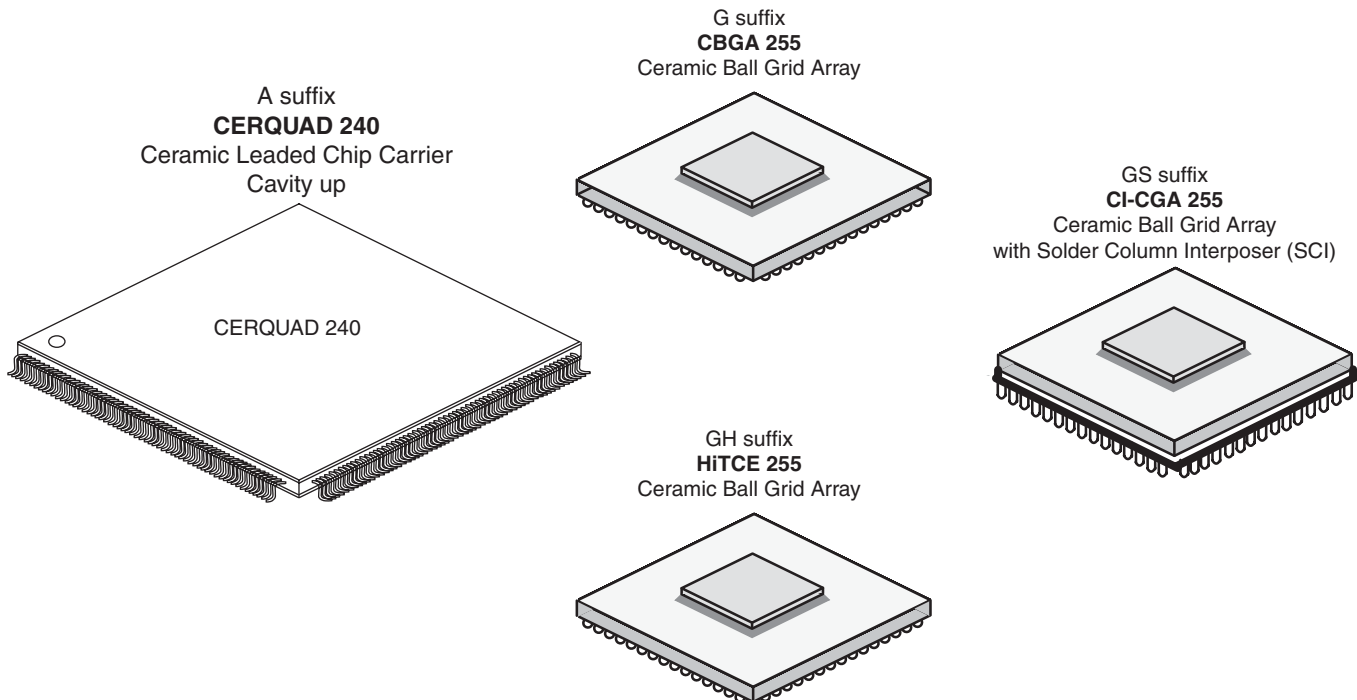


The 603R uses an advanced, 2.5/3.3V CMOS process technology and maintains full interface compatibility with TTL devices. It also integrates in-system testability and debugging features through JTAG boundary-scan capabilities.

2. Screening/Quality/Packaging

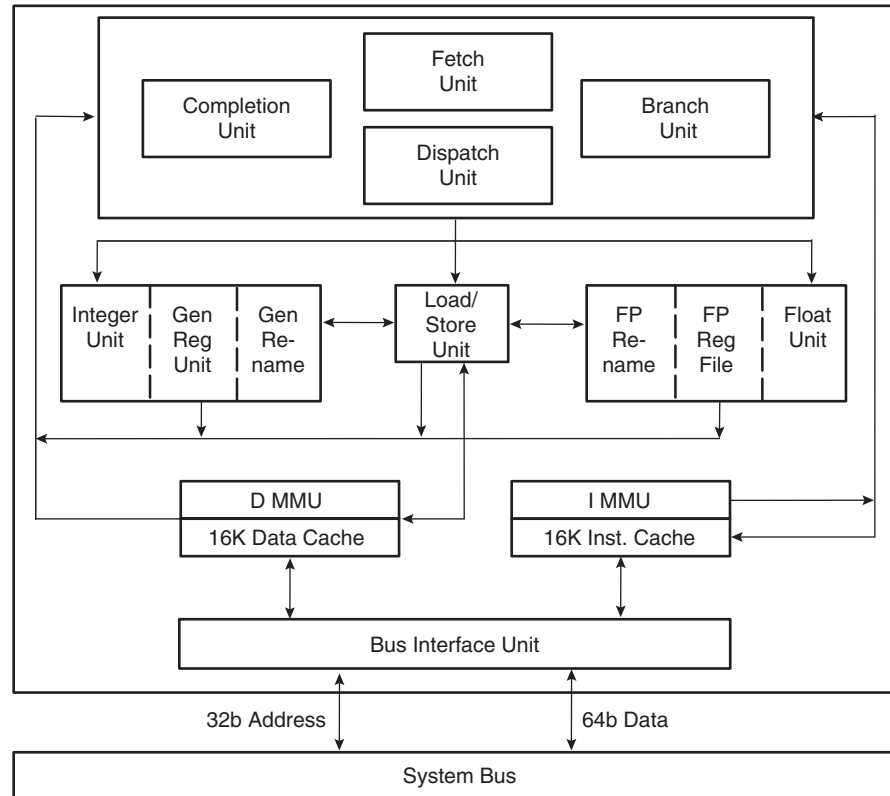
This product is manufactured in full compliance with:

- HiTCE CBGA according to Atmel Standards
- CI-CGA 255 and Cerquad: MIL-PRF-38535 class Q or according to Atmel standards
- CBGA 255: Upscreenings based upon Atmel standards
- CBGA, CI-CGA, HiTCE packages:
 - Full military temperature range ($T_C = -55^{\circ}\text{C}$, $T_J = +125^{\circ}\text{C}$)
 - Industrial temperature range ($T_C = -40^{\circ}\text{C}$, $T_J = +110^{\circ}\text{C}$)
- Cerquad:
 - Full military temperature range ($T_C = -55^{\circ}\text{C}$, $T_C = +125^{\circ}\text{C}$)
 - Industrial temperature range ($T_C = -40^{\circ}\text{C}$, $T_C = +110^{\circ}\text{C}$)
 - Commercial temperature ranges ($T_C = 0^{\circ}\text{C}$, $T_C = +70^{\circ}\text{C}$)
- Internal I/O Power Supply = 2.5 \pm 5% // 3.3V \pm 5%



3. Block Diagram

Figure 3-1. Block Diagram



4. Overview

The 603R is a low-power implementation of the PowerPC microprocessor family of Reduced Instruction Set Computing (RISC) microprocessors. The 603R implements the 32-bit portion of the PowerPC architecture, which provides 32-bit effective addresses, integer data types of 8, 16 and 32 bits, and floating-point data types of 32 and 64 bits. For 64-bit PowerPC microprocessors, the PowerPC architecture provides 64-bit integer data types, 64-bit addressing, and other features required to complete the 64-bit architecture.

The 603R provides four software controllable power-saving modes. Three of the modes (nap, doze, and sleep) are static in nature, and progressively reduce the amount of power dissipated by the processor. The fourth is a dynamic power management mode that causes the functional units in the 603R to automatically enter a low-power mode when the functional units are idle without affecting operational performance, software execution, or any external hardware.

The 603R is a superscalar processor capable of issuing and retiring as many as three instructions per clock. Instructions can be executed in any order for increased performance, but, the 603R makes completion appear sequential.

The 603e integrates five execution units:

- an Integer Unit (IU)
- a Floating-point Unit (FPU)
- a Branch Processing Unit (BPU)

- a Load/Store Unit (LSU)
- a System Register Unit (SRU)

The ability to execute five instructions in parallel and the use of simple instructions with rapid execution times yield high efficiency and throughput for 603R-based systems. Most integer instructions execute in one clock cycle. The FPU is pipelined so a single-precision multiply-add instruction can be issued every clock cycle.

The 603R provides independent on-chip, 16 Kbyte, four-way set-associative, physically addressed caches for instructions and data, as well as on-chip instruction and data Memory Management Units (MMUs). The MMUs contain 64-entry, two-way set-associative, Data and Instruction Translation Lookaside Buffers (DTLB and ITLB) that provide support for demand-paged virtual memory address translation and variable-sized block translation. The TLBs and caches use a Least Recently Used (LRU) replacement algorithm. The 603R also supports block address translation through the use of two independent Instruction and Data Block Address Translation (IBAT and DBAT) arrays of four entries each. Effective addresses are compared simultaneously with all four entries in the BAT array during block translation. In accordance with the PowerPC architecture, if an effective address hits in both the TLB and BAT array, the BAT translation has priority.

The 603R has a selectable 32- or 64-bit data bus and a 32-bit address bus. The 603R interface protocol allows multiple masters to compete for system resources through a central external arbiter. The 603R provides a three-state coherency protocol that supports the exclusive, modified, and invalid cache states. This protocol is a compatible subset of the MESI (Modified/Exclusive/Shared/Invalid) four-state protocol and operates coherently in systems that contain four-state caches. The 603R supports single-beat and burst data transfers for memory accesses, and supports memory-mapped I/Os.

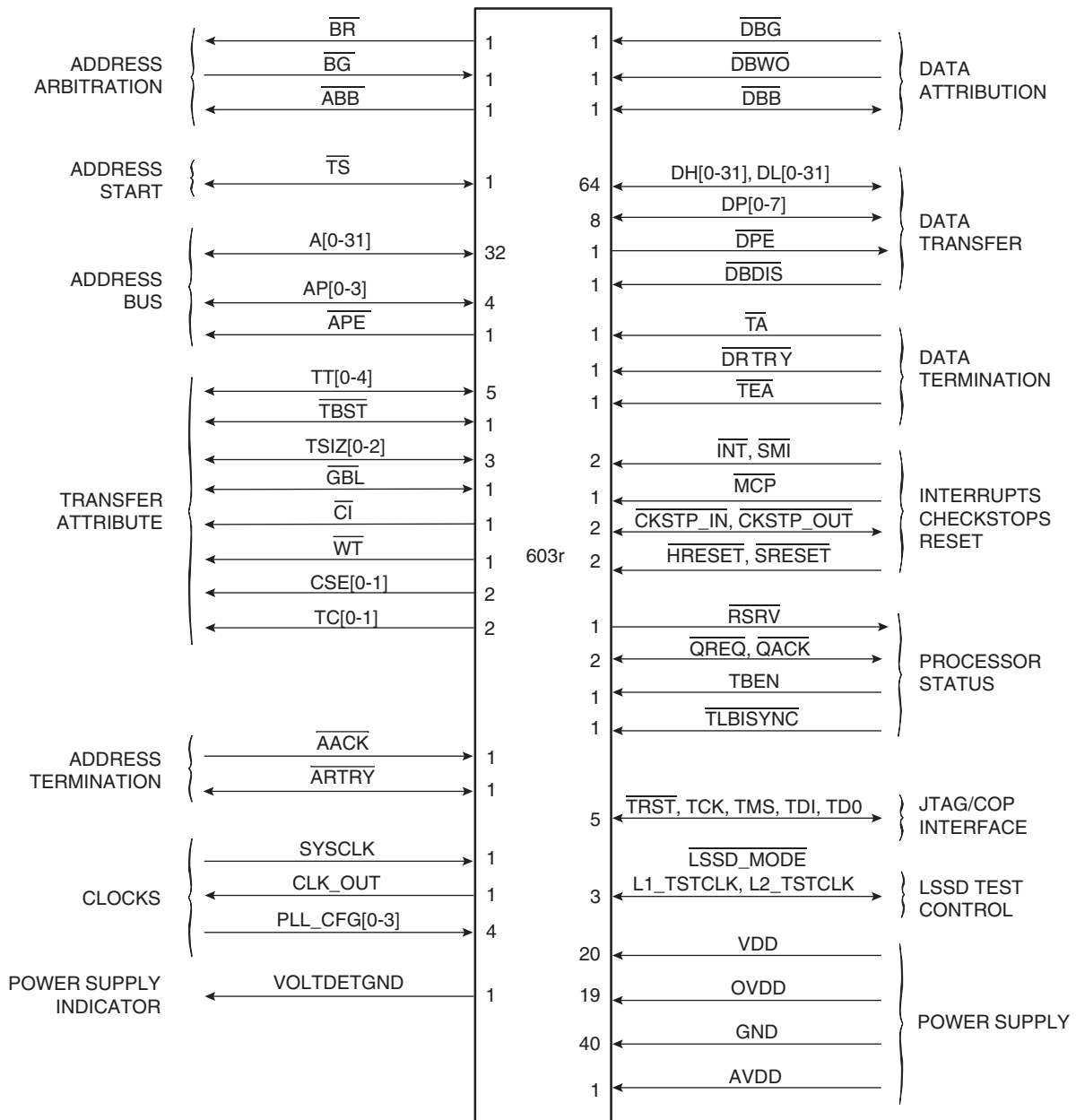
The 603R uses an advanced, 0.29 μm 5-metal-layer CMOS process technology and maintains full interface compatibility with TTL devices.

5. Signal Description

[Figure 5-1 on page 5](#), [Table 10-5](#) and [Table 10-6 on page 20](#) describe the signals on the TSPC603R and indicate signal functions. The test signals, $\overline{\text{TRST}}$, TMS, TCK, TDI and TDO, comply with the subset P-1149.1 of the IEEE testability bus standard.

The three signals $\overline{\text{LSSD_MODE}}$, LI_TSTCLK and L2_TSTCLK are test signals for factory use only and must be pulled up to V_{DD} for normal machine operations.

Figure 5-1. Functional Signal Groups



6. Detailed Specifications

This specification describes the specific requirements for the microprocessor TSPC603R, in compliance with MIL-STD-883 class B or Atmel standard screening.

7. Applicable Documents

1. MIL-STD-883: Test methods and procedures for electronics
2. MIL-PRF-38535: General specifications for microcircuits

The microcircuits are in accordance with the applicable documents and as specified herein.

7.1 Design and Construction

7.1.1 Terminal Connections

Depending on the package, the terminal connections are as shown in [Table 10-2 on page 15](#), [Table 10-4 on page 18](#), "Recommended Operating Conditions" on page 6, [Figure 15-2 on page 49](#), [Figure 15-4 on page 52](#) and [Figure 5-1 on page 5](#).

7.1.2 Lead Material and Finish

Lead material and finish shall be as specified in MIL-STD-1835. (See "Package Mechanical Data" on page 47.)

7.2 Absolute Maximum Ratings

Absolute maximum ratings are stress ratings only and functional operation at the maximum is not guaranteed. Stresses beyond those listed may affect device reliability or cause permanent damage to the device.

7.2.1 Absolute Maximum Ratings for the 603R⁽¹⁾⁽²⁾⁽³⁾

Parameter	Symbol	Min	Max	Unit
Core supply voltage	V_{DD}	-0.3	2.75	V
PLL supply voltage	AV_{DD}	-0.3	2.75	V
I/O supply voltage	OV_{DD}	-0.3	3.6	V
Input voltage	V_{IN}	-0.3	5.5	V
Storage temperature range	T_{STG}	-55	+150	°C

- Notes:
- Caution:** The input voltage must not be greater than OV_{DD} by more than 2.5V at any time, including during power-on reset.
 - Caution:** The OV_{DD} voltage must not be greater than V_{DD}/AV_{DD} by more than 1.2V at any time, including during power-on reset.
 - Caution:** The V_{DD}/AV_{DD} voltage must not be greater than OV_{DD} by more than 0.4V at any time, including during power-on reset.

Functional operating conditions are given in AC and DC electrical specifications. Stresses beyond the absolute maximums listed may affect device reliability or cause permanent damage to the device.

7.2.2 Recommended Operating Conditions

The following are the recommended and tested operating conditions. Proper device operation outside of these ranges is not guaranteed.

7.2.3 Recommended Operating Conditions

Parameter	Symbol	Min	Max	Unit
Core supply voltage	V_{DD}	2.375	2.625	V
PLL supply voltage	AV_{DD}	2.375	2.625	V
I/O supply voltage	OV_{DD}	3.135	3.465	V
Input voltage	V_{IN}	GND	5.5	V
Operating temperature	T_c	-55	+125	°C
Junction operating temperature specific to Cerquad	T_j	–	+135	°C

8. Thermal Characteristics

8.1 CBGA 255 and CI-CGA 255 Packages

The data found in this section concerns 603R devices packaged in the 255-lead 21 mm multi-layer ceramic (MLC) and ceramic BGA package. Data is included for use with a Thermalloy #2328B heat sink.

The internal thermal resistance for this package is negligible due to the exposed die design. A thermal interface material is recommended at the package lid to heat sink interface to minimize the thermal contact resistance.

Additionally, the CBGA package offers an excellent thermal connection to the card and power planes. Heat generated at the chip is dissipated through the package, the heat sink (when used) and the card. The parallel heat flow paths result in the lowest overall thermal resistance as well as offer significantly better power dissipation capability if a heat sink is not used.

The thermal characteristics for the flip-chip CBGA and CI-CGA packages are as follows:

Thermal resistance (junction-to-case) = R_{jc} or
 $\theta_{jc} = 0.095^{\circ}\text{C/Watt}$ for the 2 packages.

Thermal resistance (junction-to-ball) = R_{jb} or
 $\theta_{jb} = 3.5^{\circ}\text{C/Watt}$ for the CBGA package.

Thermal resistance (junction-to-bottom SCI) = R_{js} or
 $\theta_{js} = 3.7^{\circ}\text{C/Watt}$ for the CI-CGA package.

The junction temperature can be calculated from the junction to ambient thermal resistance, as follow:

Junction temperature:

$$T_j = T_a + (R_{jc} + R_{cs} + R_{sa}) \times P$$

where: T_a is the ambient temperature in the vicinity of the device
 R_{jc} is the die junction to case thermal resistance of the device
 R_{cs} is the case to heat sink thermal resistance of the interface material
 R_{sa} is the heat sink to ambient thermal resistance
 P is the power dissipated by the device

During operation, the die-junction temperatures (T_j) should be maintained at a lower value than the value specified in "[Recommended Operating Conditions](#)" on page 6.

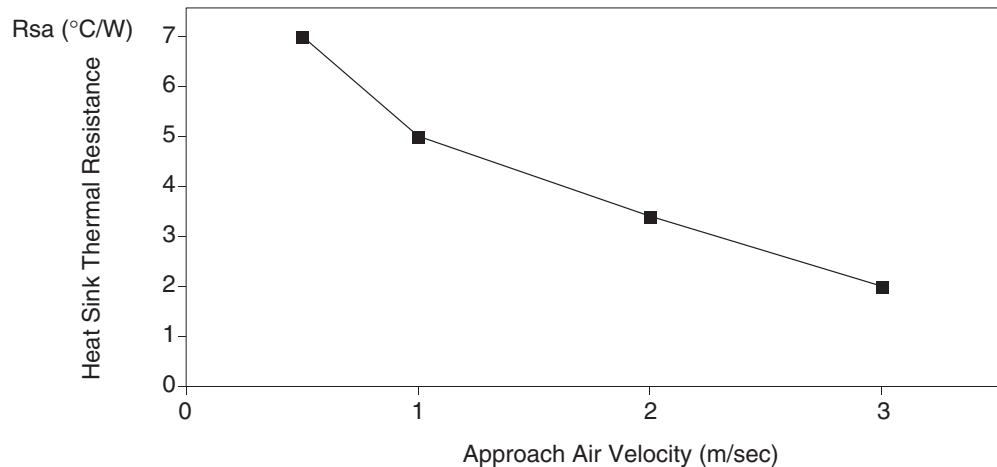
The thermal resistance of the thermal interface material (R_{cs}) is typically about 1°C/Watt .

Assuming a T_a of 85°C and a consumption (P) of 3.6 Watts, the junction temperature of the device would be as follow:

$$T_j = 85^{\circ}\text{C} + (0.095^{\circ}\text{C/Watt} + 1^{\circ}\text{C/Watt} + R_{sa}) \times 3.5 \text{ Watts.}$$

For the Thermalloy heat sink #2328B, the heat sink-to-ambient thermal resistance (R_{sa}) versus airflow velocity is shown in [Figure 8-1](#).

Figure 8-1. CBGA Thermal Management Example



Assuming an air velocity of 1 m/sec, the associated overall thermal resistance and junction temperature, found in [Table 8-1](#) will result.

Table 8-1. Thermal Resistance and Junction Temperature

Configuration	R_{ja} (°C/W)	T_j (°C)
With 2328B heat sink	5	106

Vendors such as Aavid, Thermalloy®, and Wakefield Engineering can supply heat sinks with a wide range of thermal performance.

8.2 HiTCE CBGA Package

Table 8-2. HiTCE CBGA Package

Characteristic	Symbol	Value	Unit
Junction-to-bottom of balls ⁽¹⁾	$R\theta_J$	7.5	°C/W
Junction-to-ambient thermal resistance natural convection, four-layer (2s2p) board	$R\theta_{JMA}$	22.4 ⁽²⁾	°C/W
Junction to board thermal resistance	$R\theta_{JB}$	11.7 ⁽³⁾	°C/W

Notes: 1. Simulation, no convection air flow.
 2. Per JEDEC JESD51-2 with the board horizontal.
 3. Per JEDEC JESD51-8 with the board horizontal.

8.3 CERQUAD 240 Package

This section provides thermal management data for the 603R. This information is based on a typical desktop configuration using a 240 lead, 32 mm x 32 mm, wire-bond CERQUAD package with the cavity up (the silicon die is attached to the bottom of the package). This configuration enables dissipation through the PCB.

The thermal characteristics for a wire-bond CERQUAD package are as follows:

- Thermal resistance (junction to bottom of the case) (typical) = $R_{\theta_{jc}}$ or $\theta_{jc} = 2.5^\circ\text{C/Watt}$
- Thermal resistance (junction to top of the case) is typically 16°C/W

8.3.1 Thermal Management Example

The junction temperature can be calculated from the junction to ambient thermal resistance, as follows:

Junction temperature:

$$T_j = T_c + R_{\theta jc} \times P$$

$$T_j = T_a + (R_{cs} + R_{sa}) \times P + R_{\theta jc} \times P$$

so

$$T_j = T_a + (R_{\theta jc} + R_{cs} + R_{sa}) \times P$$

Where:

T_a is the ambient temperature in the vicinity of the device

$R_{\theta ja}$ is the junction to ambient resistance

$R_{\theta jc}$ is the junction to case thermal resistance of the device

R_{cs} is the case to heat sink thermal resistance of the interface material

R_{sa} is the heat sink to ambient thermal resistance

P is the power dissipated by the device

Because dissipation is made through the PCB, R_{cs} and R_{sa} are user values, and can vary considerably depending on the customer's application.

In a typical customer application, if R_{cs} is 0.5°C/W, R_{sa} is 3°C/W and T_a is 110°C, T_j can be estimated.

$$T_j = 110^\circ\text{C} + (2.5 + 0.5 + 3) \times 2.5 = 125^\circ\text{C}$$

Note that verification of external thermal resistance and case temperature should be performed for each application. Thermal resistance depends on many factors including the amount of air turbulence and can therefore vary considerably.

9. Power Consideration

The PowerPC 603R is a microprocessor specifically designed for low-power operation. Like the 603e microprocessor version, the 603R provides both automatic and program-controllable power reduction modes for progressive reduction of power consumption. This section describes the hardware support provided by the 603R for power management.

9.1 Dynamic Power Management

Dynamic power management automatically powers up and down the individual execution units of the 603R, based upon the contents of the instruction stream. For example, if no floating-point instructions are being executed, the floating-point unit is automatically powered down. Power is not actually removed from the execution unit; instead, each execution unit has an independent clock input, which is automatically controlled on a clock-by-clock basis. Since CMOS circuits consume negligible power when they are not switching, stopping the clock to an execution unit effectively eliminates its power consumption. The operation of DPM is completely transparent to software or any external hardware. Dynamic power management is enabled by setting bit 11 in H1D0 on power-up, following $\overline{\text{HRESET}}$.

9.2 Programmable Power Modes

The 603R provides four programmable power states, full power, doze, nap and sleep. The software selects these modes by setting one (and only one) of the three power saving mode bits. The hardware can enable a power management state through external asynchronous interrupts. The hardware interrupt causes the transfer of program flow to interrupt the handler code. The appropriate mode is then set by the software. The 603R provides a separate interrupt and interrupt vector for power management, the System Management Interrupt (SMI). The 603R also contains a decrement timer which allows it to enter the nap or doze mode for a predetermined amount of time and then return to full power operation through the Decrementer Interrupt (DI). Note that the 603R cannot switch from power-on management mode to another without first returning to full on mode. The nap and sleep modes disable bus snooping; therefore, a hardware handshake is provided to ensure coherency before the 603R enters these power management modes.

Table 9-1 summarizes the four power states.

Table 9-1. Power PC 603R Microprocessor Programmable Power Modes

PM Mode	Functioning Units	Activation Method	Full-power Wake-up Method
Full Power	All units active	–	–
Full Power (with DPM)	Requested logic by demand	By instruction dispatch	–
Doze	- Bus snooping - Data cache as needed - Decrementer timer	Controlled by SW	External asynchronous exceptions ⁽¹⁾ Decrementer interrupt Reset
Nap	Decrementer timer	Controlled by hardware and software	External asynchronous exceptions Decrementer interrupt Reset
Sleep	None	Controlled by hardware and software	External asynchronous exceptions Reset

Note: 1. Exceptions are referred to as interrupts in the architecture specification.

9.3 Power Management Modes

The following describes the characteristics of the 603R's power management modes, the requirements for entering and exiting the various modes, and the system capabilities provided by the 603R while the power management modes are active.

Full Power Mode with DPM Disabled

Full power mode with DPM disabled; power mode is selected when the DPM enable bit (bit 11) in HID0 is cleared

- Default state following power-up and $\overline{\text{HRESET}}$
- All functional units are operating at full processor speed at all times

Full Power Mode with DPM Enabled

Full power mode with DPM enabled (HID0[11] = 1); provides on-chip power management without affecting the functionality or performance of the 603R

- Required functional units are operating at full processor speed

- Functional units are clocked only when needed
- No software or hardware intervention required after mode is set
- Software/hardware and performance are transparent

Doze Mode

The doze mode disables most functional units but maintains cache coherency by enabling the bus interface unit and snooping. A snoop hit will cause the 603R to enable the data cache, copy the data back to the memory, disable the cache, and fully return to the doze state. In this mode:

- Most functional units are disabled
- Bus snooping and time base/decrementer are still enabled
- Doze mode sequence:
 - Set doze bit (HID0[8] = 1)
 - 603R enters doze mode after several processor clocks
- There are several methods for returning to full-power mode
 - Assert $\overline{\text{INT}}$, $\overline{\text{SMI}}$, $\overline{\text{MCP}}$ or decremter interrupts
 - Assert hard reset or soft reset
- The Transition to full-power state takes no more than a few processor cycles
- Phase Locked Loop (PLL) running and locked to SYSCLK

Nap Mode

The nap mode disables the 603R but still maintains the phase locked loop (PLL) and the time base/decrementer. The time base can be used to restore the 603R to full-on state after a programmed amount of time. Because bus snooping is disabled for nap and sleep modes, a hardware handshake using the quiesce request ($\overline{\text{QREQ}}$) and quiesce acknowledge ($\overline{\text{QACK}}$) signals is required to maintain data coherency. The 603R will assert the $\overline{\text{QREQ}}$ signal to indicate that it is ready to disable bus snooping. When the system has ensured that snooping is no longer necessary, it will assert $\overline{\text{QACK}}$ and the 603R will enter the sleep or nap mode. In this mode:

- The time base/decrementer is still enabled
- Most functional units are disabled (including bus snooping)
- All non-essential input receivers are disabled
- Nap mode sequence:
 - Set nap bit (HID0[9] = 1)
 - 603R asserts quiesce request ($\overline{\text{QREQ}}$) signal
 - System asserts quiesce acknowledge ($\overline{\text{QACK}}$) signal
 - 603R enters sleep mode after several processor clocks
- There are several methods for returning to full-power mode:
 - Assert $\overline{\text{INT}}$, $\overline{\text{SPI}}$, $\overline{\text{MCP}}$ or decremter interrupts
 - Assert hard reset or soft reset
- Transition to full-power takes no more than a few processor cycles
- The PLL is running and locked to SYSCLK

Sleep Mode

Sleep mode consumes the least amount of power of the four modes since all functional units are disabled. To conserve the maximum amount of power, the PLL may be disabled and the SYSCLK may be removed. Due to the fully static design of the 603R, the internal processor state is preserved when no internal clock is present. Because the time base and decremter are disabled while the 603R is in sleep mode, the 603R's time base contents will have to be updated from an external time base following sleep mode if accurate time-of-day maintenance is required. Before the 603R enters the sleep mode, the 603R will assert the \overline{QREQ} signal to indicate that it is ready to disable bus snooping. When the system has ensured that snooping is no longer necessary, it will assert \overline{QACK} and the 603R will enter the sleep mode.

In this mode:

- All functional units are disabled (including bus snooping and time base)
- All non-essential input receivers are disabled
 - Internal clock regenerators are disabled
 - The PLL is still running (see below)
- Sleep mode sequence
 - Set sleep bit ($HID0[10] = 1$)
 - 603R asserts quiesce request (\overline{QREQ})
 - System asserts quiesce acknowledge (\overline{QACK})
 - 603R enters sleep mode after several processor clocks
- There are several methods for returning to full-power mode
 - Assert \overline{INT} , \overline{SMI} , or \overline{MCP} interrupts
 - Assert hard reset or soft reset
- The PLL may be disabled and SYSCLK may be removed while in sleep mode
- Return to full-power mode after PLL and SYSCLK disabled in sleep mode
 - Enable SYSCLK
 - Reconfigure PLL into the desired processor clock mode
 - System logic waits for PLL startup and relock time (100 μ s)
 - System logic asserts one of the sleep recovery signals (for example, INT or SMI)

9.4 Power Management Software Considerations

Since the 603R is a dual issue processor with out-of-order execution capabilities, care must be taken with the way the power management mode is entered. Furthermore, nap and sleep modes require all outstanding bus operations to be completed before the power management mode is entered. Normally, during the system configuration time, one of the power management modes would be selected by setting the appropriate $HID0$ mode bit. Later on, the power management mode is invoked by setting the $MSR[POW]$ bit. To provide a clean transition into and out of the power management mode, the **stmsr**[POW] should be preceded by a **sync** instruction and followed by an **isync** instruction.

9.5 Power Dissipation

Table 9-2. Power Dissipation⁽¹⁾⁽²⁾⁽³⁾⁽⁴⁾ with $V_{DD}/AV_{DD} = 2.5 \pm 5\%V$, $OV_{DD} = 3.3 \pm 5\%V$, $GND = 0V$, $0^{\circ}C \leq T_C \leq 125^{\circ}C$

CPU Clock Frequency	Cerquad 240 Package		CBGA 255, HiTCE CBGA 255 and CI-CGA 255					Units
	166 MHz	200 MHz	166 MHz	200 MHz	233 MHz	266 MHz	300 MHz	
Full-on Mode (DPM Enabled)								
Typical	2.1	2.5	2.1	2.5	3	3.5	4	W
Max	3.2	4	3.2	4	4.6	5.3	6	W
Doze Mode								
Typical	1.5	1.7	1.5	1.7	1.8	2	2.1	W
Nap Mode								
Typical	100	120	100	120	140	160	180	mW
Sleep Mode								
Typical	96	110	96	110	123	135	150	mW
Sleep Mode-PLL Disabled								
Typical	60	60	60	60	60	60	60	mW
Sleep Mode-PLL and SYSCLK Disabled								
Typical	25	25	25	25	25	25	25	mW
Maximum	60	60	60	60	60	80	100	mW

- Notes:
1. These values apply for all valid PLL_CFG[0-3] settings and do not include output driver power (OV_{DD}) or analog supply power (AV_{DD}). OV_{DD} power is system dependent but is typically $\leq 10\%$ of V_{DD} . Worst case $AV_{DD} = 15$ mW.
 2. Typical power is an average value measured at $V_{DD} = AV_{DD} = 2.5V$, $OV_{DD} = 3.3V$, in a system executing typical applications and benchmark sequences.
 3. Maximum power is measured at $V_{DD} = 2.625V$ using a worst-case instruction mix.
 4. To calculate the power consumption at low temperature ($-55^{\circ}C$), **use a factor of 1.25.**

9.6 Marking

Each microcircuit is legible and permanently marked with at least the following information:

- Atmel logo
- Manufacturer's part number
- Class B identification if applicable
- Date code of inspection lot
- ESD identifier if available
- Country of manufacture

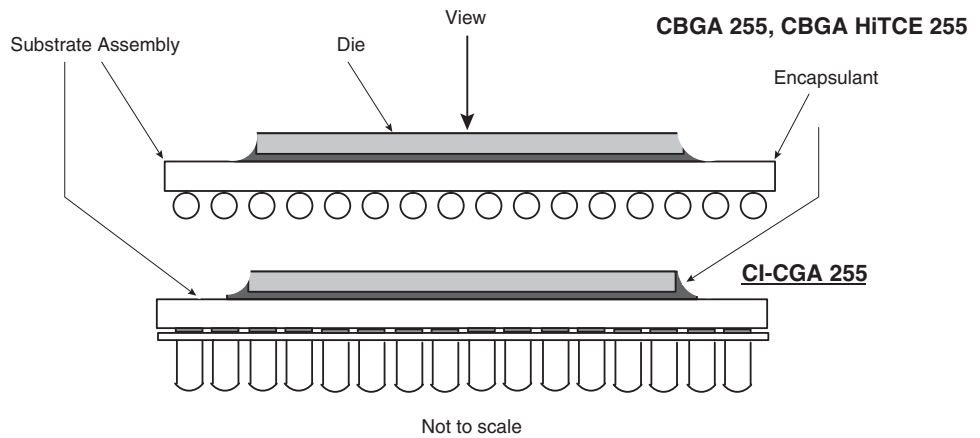
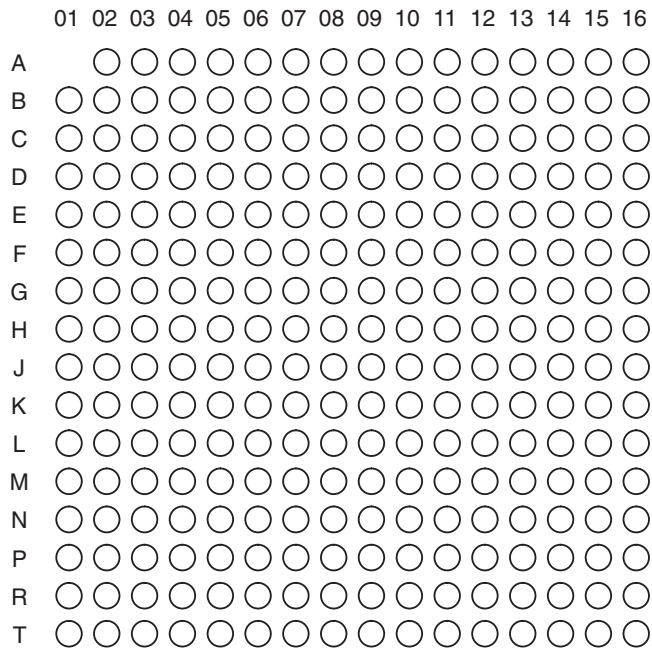
10. Pin Assignments

10.1 CBGA 255 and CI-CGA 255 Packages

Figure 10-1 (pin matrix) shows the pinout as viewed from the top of the CBGA and CI-CGA packages. The direction of the top surface view is shown by the side profile of the packages.

Figure 10-1. CBGA 255, HiTCE CBGA 255 and CI-CGA 255 Top View

Pin matrix top view



10.1.1 Pinout Listing

Table 10-1. Power and Ground Pins

	CBGA, HiTCE CBGA and CI-CGA Pin Number	
	V _{DD}	GND
PLL (AV _{DD})	A10	
Internal Logic ⁽¹⁾ (V _{DD})	F06, F08, F09, F11, G07, G10, H06, H08, H09, H11, J06, J08, J09, J11, K07, K10, L06, L08, L09, L11	C05, C12, E03, E06, E08, E09, E11, E14, F05, F07, F10, F12, G06, G08, G09, G11, H05, H07, H10, H12, J05, J07, J10, J12, K06, K08, K09, K11, L05, L07, L10, L12, M03, M06, M08, M09, M11, M14, P05, P12
I/O Drivers ⁽¹⁾ (OV _{DD})	C07, E05, E07, E10, E12, G03, G05, G12, G14, K03, K05, K12, K14, M05, M07, M10, M12, P07, P10	

Notes: 1. OV_{DD} inputs apply power to the I/O drivers and V_{DD} inputs supply power to the processor core.

Table 10-2. Signal Pinout Listing

Signal Name	CBGA, HiTCE CBGA and CI-CGA Pin Number	Active	I/O
A[0-31]	C16, E04, D13, F02, D14, G01, D15, E02, D16, D04, E13, G02, E15, H01, E16, H02, F13, J01, F14, J02, F15, H03, F16, F04, G13, K01, G15, K02, H16, M01, J15, P01	High	I/O
$\overline{\text{AACK}}$	L02	Low	Input
$\overline{\text{ABB}}$	K04	Low	I/O
AP[0-3]	C01, B04, B03, B02	High	I/O
$\overline{\text{APE}}$	A04	Low	Output
$\overline{\text{ARTRY}}$	J04	Low	I/O
$\overline{\text{BG}}$	L01	Low	Input
$\overline{\text{BR}}$	B06	Low	Output
$\overline{\text{CI}}$	E01	Low	Output
$\overline{\text{CKSTP_IN}}$	D08	Low	Input
$\overline{\text{CKSTP_OUT}}$	A06	Low	Output
CLK_OUT	D07	-	Output
CSE[0-1]	B01, B05	High	Output
$\overline{\text{DBB}}$	J14	Low	I/O
$\overline{\text{DBG}}$	N01	Low	Input
$\overline{\text{DBDIS}}$	H15	Low	Input
$\overline{\text{DBWO}}$	G04	Low	Input
DH[0-31]	P14, T16, R15, T15, R13, R12, P11, N11, R11, T12, T11, R10, P09, N09, T10, R09, T09, P08, N08, R08, T08, N07, R07, T07, P06, N06, R06, T06, R05, N05, T05, T04	High	I/O
DL[0-31]	K13, K15, K16, L16, L15, L13, L14, M16, M15, M13, N16, N15, N13, N14, P16, P15, R16, R14, T14, N10, P13, N12, T13, P03, N03, N04, R03, T01, T02, P04, T03, R04	High	I/O
DP[0-7]	M02, L03, N02, L04, R01, P02, M04, R02	High	I/O
$\overline{\text{DPE}}$	A05	Low	Output
$\overline{\text{DRTRY}}$	G16	Low	Input

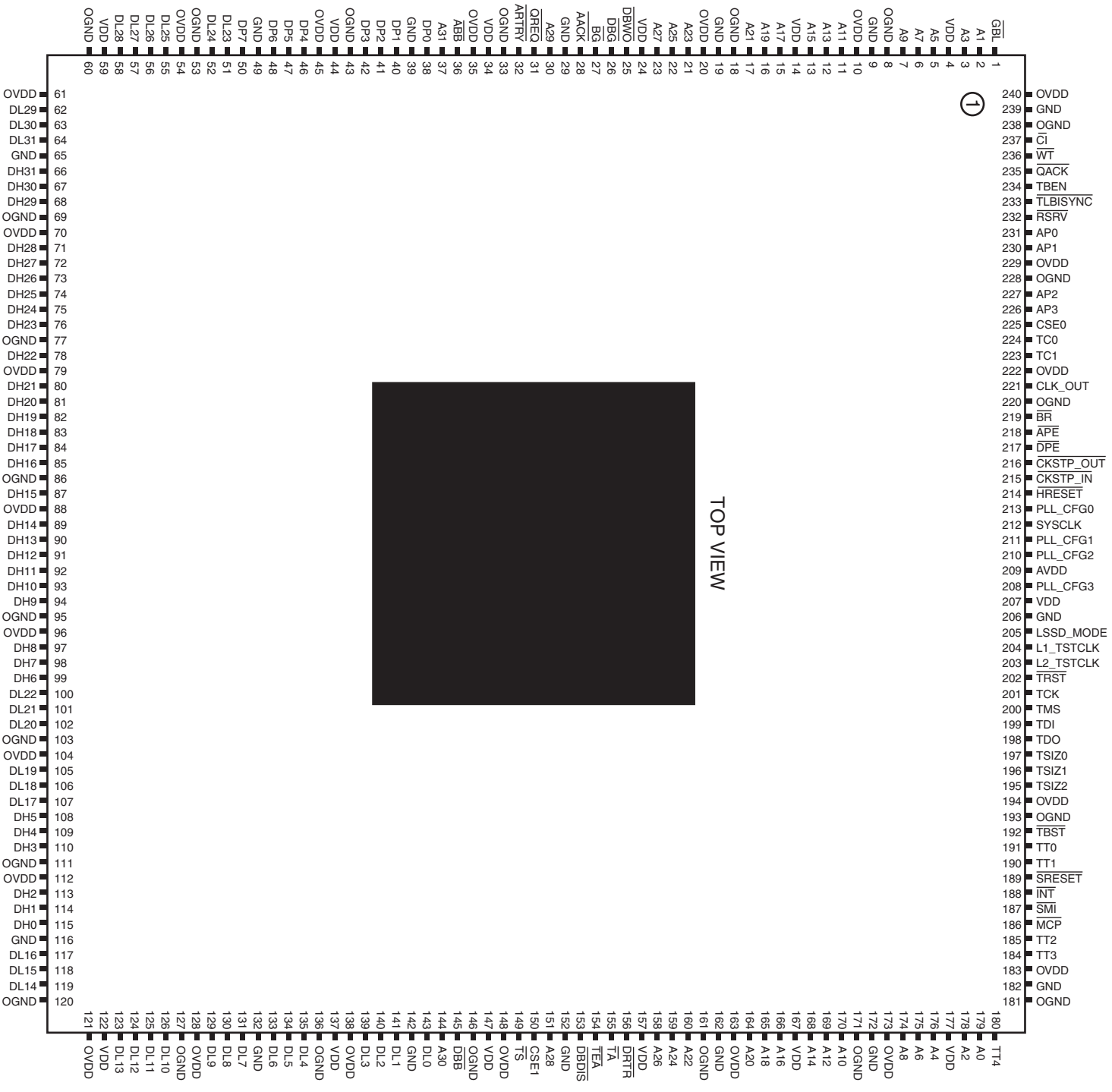
Table 10-2. Signal Pinout Listing (Continued)

Signal Name	CBGA, HITCE CBGA and CI-CGA Pin Number	Active	I/O
$\overline{\text{GBL}}$	F01	Low	I/O
$\overline{\text{HRESET}}$	A07	Low	Input
$\overline{\text{INT}}$	B15	Low	Input
L1_TSTCLK ⁽¹⁾	D11	-	Input
L2_TSTCLK ⁽¹⁾	D12	-	Input
$\overline{\text{LSSD_MODE}}^{(1)}$	B10	Low	Input
$\overline{\text{MCP}}$	C13	Low	Input
PLL_CFG[0-3]	A08, B09, A09, D09	High	Input
$\overline{\text{QACK}}$	D03	Low	Input
$\overline{\text{QREQ}}$	J03	Low	Output
$\overline{\text{RSRV}}$	D01	Low	Output
$\overline{\text{SMI}}$	A16	Low	Input
$\overline{\text{SRESET}}$	B14	Low	Input
SYSCLK	C09	-	Input
$\overline{\text{TA}}$	H14	Low	Input
TBEN	C02	High	Input
$\overline{\text{TBST}}$	A14	Low	I/O
TC[0-1]	A02, A03	High	Output
TCK	C11	-	Input
TDI	A11	High	Input
TDO	A12	High	Output
$\overline{\text{TEA}}$	H13	Low	Input
$\overline{\text{TLBISYNC}}$	C04	Low	Input
TMS	B11	High	Input
$\overline{\text{TRST}}$	C10	Low	Input
$\overline{\text{TS}}$	J13	Low	I/O
TSIZ[0-2]	A13, D10, B12	High	I/O
TT[0-4]	B13, A15, B16, C14, C15	High	I/O
$\overline{\text{WT}}$	D02	Low	Output
NC	B07, B08, C03, C06, C08, D05, D06, F03, H04, J16	Low	Input
VOLTDETGND ⁽²⁾	F03	Low	Output

- Notes:
1. These are test signals for factory use only and must be pulled up to OV_{DD} for normal machine operation.
 2. NC (not connected) in the 603e BGA package; internally tied to GND in the 603R BGA package to indicate to the power supply that a low-voltage processor is present.

10.2 CERQUAD 240 Package

Figure 10-2. CERQUAD 240: Top View





10.2.1 Pinout Listing

Table 10-3. Power and Ground Pins

	CERQUAD Pin Number	
	VCC	GND
PLL (AV _{DD})	209	
Internal Logic	4, 14, 24, 34, 44, 59, 122, 137, 147, 157, 167, 177, 207	9, 19, 29, 39, 49, 65, 116, 132, 142, 152, 162, 172, 182, 206, 239
Output Drivers	10, 20, 35, 45, 54, 61, 70, 79, 88, 96, 104, 112, 121, 128, 138, 148, 163, 173, 183, 194, 222, 229, 240	8, 18, 33, 43, 53, 60, 69, 77, 86, 95, 103, 111, 120, 127, 136, 146, 161, 171, 181, 193, 220, 228, 238

Table 10-4. Signal Pinout Listing

Signal Name	CERQUAD Pin Number
A[0-31]	179, 2, 178, 3, 176, 5, 175, 6, 174, 7, 170, 11, 169, 12, 168, 13, 166, 15, 165, 16, 164, 17, 160, 21, 159, 22, 158, 23, 151, 30, 144, 37
$\overline{\text{AACK}}$	28
$\overline{\text{ABB}}$	36
AP[0-3]	231, 230, 227, 226
$\overline{\text{APE}}$	218
$\overline{\text{ARTRY}}$	32
$\overline{\text{BG}}$	27
$\overline{\text{BR}}$	219
$\overline{\text{CI}}$	237
$\overline{\text{CKSTP_IN}}$	215
$\overline{\text{CKSTP_OUT}}$	216
CLK_OUT	221
CSE[0-1]	225, 150
$\overline{\text{DBB}}$	145
$\overline{\text{DBG}}$	26
$\overline{\text{DBDIS}}$	153
$\overline{\text{DBWO}}$	25
DH[0-31]	115, 114, 113, 110, 109, 108, 99, 98, 97, 94, 93, 92, 91, 90, 89, 87, 85, 84, 83, 82, 81, 80, 78, 76, 75, 74, 73, 72, 71, 68, 67, 66
DL[0-31]	143, 141, 140, 139, 135, 134, 133, 131, 130, 129, 126, 125, 124, 123, 119, 118, 117, 107, 106, 105, 102, 101, 100, 51, 52, 55, 56, 57, 58, 62, 63, 64
DP[0-7]	38, 40, 41, 42, 46, 47, 48, 50
$\overline{\text{DPE}}$	217
$\overline{\text{DRTRY}}$	156
$\overline{\text{GBL}}$	1
$\overline{\text{HRESET}}$	214

Table 10-4. Signal Pinout Listing (Continued)

Signal Name	CERQUAD Pin Number
$\overline{\text{INT}}$	188
L1_TSTCLK ⁽¹⁾	204
L2_TSTCLK ⁽¹⁾	203
$\overline{\text{LSSD_MODE}}^{(1)}$	205
$\overline{\text{MCP}}$	186
PLL_CFG[0-3]	213, 211, 210, 208
$\overline{\text{QACK}}$	235
$\overline{\text{QREQ}}$	31
$\overline{\text{RSRV}}$	232
$\overline{\text{SMI}}$	187
$\overline{\text{SRESET}}$	189
SYSCLK	212
$\overline{\text{TA}}$	155
TBEN	234
$\overline{\text{TBST}}$	192
TC[0-1]	224, 223
TCK	201
TDI	199
TDO	198
$\overline{\text{TEA}}$	154
$\overline{\text{TLBISYNC}}$	233
TMS	200
$\overline{\text{TRST}}$	202
$\overline{\text{TS}}$	149
TSIZ[0-2]	197, 196, 195
TT[0-4]	191, 190, 185, 184, 180
$\overline{\text{WT}}$	236
NC	

- Notes:
1. These are test signals for factory use only and must be pulled up to V_{DD} for normal machine operation.
 2. OV_{DD} inputs supply power to the I/O drivers and V_{DD} inputs supply power to the processor core. Future members of the 603 family may use different OV_{DD} and V_{DD} input levels.

Table 10-5. Address and Data Bus Signal Index for Cerquad, CBGA 255 and CI-CGA 255 Packages

Signal Name	Abbreviation	Signal Function	Signal Type
Address Bus	A[0-31]	If output, physical address of data to be transferred If input, represents the physical address of a snoop operation	I/O
Data Bus	DH[0-31]	Represents the state of data, during a data write operation if output, or during a data read operation if input	I/O
Data Bus	DL[0-31]	Represents the state of data, during a data write operation if output, or during a data read operation if input	I/O

Table 10-6. Signal Index for Cerquad, CBGA 255, HiTCE CBGA 255 and CI-CGA 255 Packages

Signal Name	Abbreviation	Signal Function	Signal Type
Address Acknowledge	\overline{AACK}	The address phase of a transaction is complete	Input
Address Bus Busy	\overline{ABB}	If output, the 603R is the address bus master If input, the address bus is in use	I/O
Address Bus Parity	AP[0-3]	If output, represents odd parity for each of 4 bytes of the physical address for a transaction If input, represents odd parity for each of 4 bytes of the physical address for snooping operations	I/O
Address Parity Error	\overline{APE}	Incorrect address bus parity detected on a snoop	Output
Address Retry	\overline{ARTRY}	If output, detects a condition in which a snooped address tenure must be retried If input, must retry the preceding address tenure	I/O
Bus Grant	\overline{BG}	May, with the proper qualification, assume mastership of the address bus	Input
Bus Request	\overline{BR}	Request mastership of the address bus	Output
Cache Inhibit	\overline{CI}	A single-beat transfer will not be cached	Output
Checkstop Input	$\overline{CKSTP_IN}$	Must terminate operation by internally gating off all clocks, and release all outputs	Input
Checkstop Output	$\overline{CKSTP_OUT}$	Has detected a checkstop condition and has ceased operation	Output
Cache Set Entry	CSE[0-1]	Cache replacement set element for the current transaction reloading into or writing out of the cache	Output
Data Bus Busy	\overline{DBB}	If output, the 603R is the data bus master If input, another device is bus master	I/O
Data Bus Disable	\overline{DBDIS}	(For a write transaction) must release data bus and the data bus parity to high impedance during the following cycle	Input
Data Bus Grant	\overline{DBG}	May, with the proper qualification, assume mastership of the data bus	Input
Data Bus Write Only	$\overline{DBW0}$	May run the data bus tenure	Input
Data Bus Parity	DP[0-7]	If output, odd parity for each of 8 bytes of data write transactions If input, odd parity for each byte of read data	I/O
Data Parity Error	\overline{DPE}	Incorrect data bus parity	Output
Data Retry	\overline{DRTRY}	Must invalidate the data from the previous read operation	Input

Table 10-6. Signal Index for Cerquad, CBGA 255, HiTCE CBGA 255 and CI-CGA 255 Packages (Continued)

Signal Name	Abbreviation	Signal Function	Signal Type
Global	$\overline{\text{GBL}}$	If output, a transaction is global If input, a transaction must be snooped by the 603R	I/O
Hard Reset	$\overline{\text{HRESET}}$	Initiates a complete hard reset operation	Input
Interrupt	$\overline{\text{INT}}$	Initiates an interrupt if bit EE of MSR register is set	Input
Factory Test	$\overline{\text{LSSD_MODE}}$	LSSD test control signal for factory use only	Input
	L1_TSTCLK	LSSD test control signal for factory use only	Input
	L2_TSTCLK	LSSD test control signal for factory use only	Input
Machine Check Interrupt	$\overline{\text{MCP}}$	Initiates a machine check interrupt operation if the bit ME of MSR register and bit EMCP of HID0 register are set	Input
PLL Configuration	PLL_CFG[0-3]	Configures the operation of the PLL and the internal processor clock frequency	Input
Power supply indicator	VOLTDETGND	Available only on BGA package Indicates to the power supply that a low-voltage processor is present.	Output
Quiescent Acknowledge	$\overline{\text{QACK}}$	All bus activity has terminated and the 603R may enter a quiescent (or low power) state	Input
Quiescent Request	$\overline{\text{QREQ}}$	Is requesting all bus activity normally to enter a quiescent (low power) state	Output
Reservation	$\overline{\text{RSRV}}$	Represents the state of the reservation coherency bit in the reservation address register	Output
System Management Interrupt	$\overline{\text{SMI}}$	Initiates a system management interrupt operation if the bit EE of MSR register is set	Input
Soft Reset	$\overline{\text{SRESET}}$	Initiates processing for a reset exception	Input
System Clock	SYSCLK	Represents the primary clock input for the 603R, and the bus clock frequency for 603R bus operation	Input
Test Clock	CLK_OUT	Provides PLL clock output for PLL testing and monitoring	Output
Transfer Acknowledge	$\overline{\text{TA}}$	A single-beat data transfer completed successfully or a data beat in a burst transfer completed successfully	Input
Timebase Enable	TBEN	The timebase should continue clocking	Input
Transfer Burst	$\overline{\text{TBST}}$	If output, a burst transfer is in progress If input, when snooping for single-beat reads	I/O
Transfer Code	TC[0-1]	Special encoding for the transfer in progress	Output
Test Clock	TCK	Clock signal for the IEEE P1149.1 test access port (TAP)	Input
Test Data Input	TDI	Serial data input for the TAP	Input
Test Data Output	TDO	Serial data output for the TAP	Output
Transfer Error Acknowledge	$\overline{\text{TEA}}$	A bus error occurred	Input
TLBI Sync	$\overline{\text{TLBISYNC}}$	Instruction execution should stop after execution of a tlbsync instruction	Input
Test Mode Select	TMS	Selects the principal operations of the test-support circuitry	Input
Test Reset	$\overline{\text{TRST}}$	Provides an asynchronous reset of the TAP controller	Input
Transfer Size	TSIZ[0-2]	For memory accesses, these signals along with $\overline{\text{TBST}}$ indicate the data transfer size for the current bus operation	I/O

Table 10-6. Signal Index for Cerquad, CBGA 255, HiTCE CBGA 255 and CI-CGA 255 Packages (Continued)

Signal Name	Abbreviation	Signal Function	Signal Type
Transfer Start	\overline{TS}	If output, begun a memory bus transaction and the address bus and transfer attribute signals are valid If input, another master has begun a bus transaction and the address bus and transfer attribute signals are valid for snooping (see \overline{GBL})	I/O
Transfer Type	TT[0-4]	Type of transfer in progress	I/O
Write-through	\overline{WT}	A single-beat transaction is write-through	Output

11. Electrical Characteristics

11.1 General Requirements

All static and dynamic electrical characteristics specified for inspection purposes and the relevant measurement conditions are given below:

- [Table 11-1](#): Static electrical characteristics for the electrical variants
- [Table 11-2](#): Dynamic electrical characteristics for the 603R

The processor core frequency is determined by the bus (SYSCLK) frequency and the settings of the PLL_CFG0 to PLL_CFG3 signals. All timings are respectively specified to the rising edge of SYSCLK.

These specifications are for 166 MHz to 300 MHz processor core frequencies for CBGA 255, HiTCE CBGA 255 and CI-CGA 255 packages and 166 MHz to 200 MHz processor core frequencies for the Cerquad 240 package.

11.2 Static Characteristics

Table 11-1. Electrical Characteristics with $V_{DD} = AV_{DD} = 2.5V \pm 5\%$; $OV_{DD} = 3.3 \pm 5\%V$, $GND = 0V$, $-55^{\circ}C \leq T_C \leq 125^{\circ}C$

Characteristics	Symbol	Min	Max	Unit	
Input High Voltage (all inputs except SYSCLK)	V_{IH}	2	5.5	V	
Input Low Voltage (all inputs except SYSCLK)	V_{IL}	GND	0.8	V	
SYSCLK Input High Voltage	CV_{IH}	2.4	5.5	V	
SYSCLK Input Low Voltage	CV_{IL}	GND	0.4	V	
Input Leakage Current	$V_{IN} = 3.465V^{(1)(3)}$	I_{IN}	-	30	μA
	$V_{IN} = 5.5V^{(1)(3)}$	I_{IN}	-	300	μA
Hi-Z (off-state) Leakage Current	$V_{IN} = 3.465V^{(1)(3)}$	I_{TSI}	-	30	μA
	$V_{IN} = 5.5V^{(1)(3)}$	I_{TSI}	-	300	μA
Output High Voltage	$I_{OH} = -7 \text{ mA}$	V_{OH}	2.4	-	V
Output Low Voltage	$I_{OL} = +7 \text{ mA}$	V_{OL}	-	0.4	V
Capacitance, $V_{IN} = 0V$, $f = 1 \text{ MHz}^{(2)}$ (excludes \overline{TS} , \overline{ABB} , \overline{DBB} , and \overline{ARTRY})	C_{IN}	-	10	pF	
Capacitance, $V_{IN} = 0V$, $f = 1 \text{ MHz}^{(2)}$ (for \overline{TS} , \overline{ABB} , \overline{DBB} , and \overline{ARTRY})	C_{IN}	-	15	pF	

Notes: 1. Excludes test signals (LSSD_MODE, L1_TSTCLK, L2_TSTCLK, and JTAG signals).
2. Capacitance is periodically sampled rather than 100% tested.

- Leakage currents are measured for nominal OV_{DD} and V_{DD} or both OV_{DD} and V_{DD} . Same variation (for example, both V_{DD} and OV_{DD} vary by either +5% or -5%)

11.3 Dynamic Characteristics

11.3.1 Clock AC Specifications

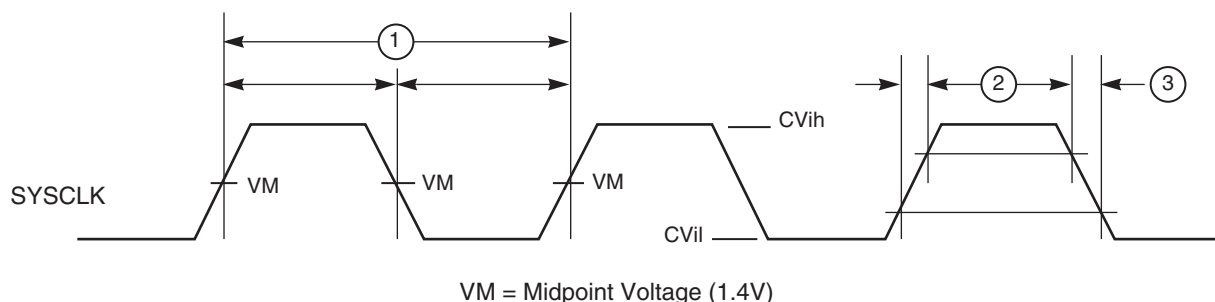
Table 11-2 provides the clock AC timing specifications as defined in Figure 11-1.

Table 11-2. Clock AC Timing Specifications⁽¹⁾⁽²⁾⁽³⁾⁽⁴⁾ with $V_{DD} = AV_{DD} = 2.5V \pm 5\%$; $OV_{DD} = 3.3 \pm 5\%V$, $GND = 0V$, $-55^{\circ}C \leq T_C \leq 125^{\circ}C$

Figure Number	Characteristics	CBGA 255, HiTCE CBGA 255, CI-CGA 255 and CERQUAD				CBGA 255, HiTCE CBGA 255 and CI-CGA 255							
		166 MHz		200 MHz		233 MHz		266 MHz		300 MHz		Unit	Note
		Min	Max	Min	Max	Min	Max	Min	Max	Min	Max		
	Processor Frequency	150	166	150	200	180	233	180	266	180	300	MHz	(5)
	VCO Frequency	300	332	300	400	360	466	360	532	360	600	MHz	(5)
	SYCLK (bus) Frequency	25	66.7	33.3	66.7	33.3	75	33.3	75	33.3	75	MHz	(5)
1	SYCLK Cycle Time	15	30	13.3	30	13.3	30	13.3	30	13.3	30	ns	
2,3	SYCLK Rise and Fall Time	–	2	–	2	–	2	–	2	–	2	ns	(1)
4	SYCLK Duty Cycle (1.4V measured)	40	60	40	60	40	60	40	60	40	60	%	(3)
	SYCLK Jitter	–	±150	–	±150	–	±150	–	±150	–	±150	ps	(2)
	603R Internal PLL Relock Time	–	100	–	100	–	100	–	100	–	100	µs	(3)(4)

- Notes:
- Rise and fall times for the SYCLK input are measured from 0.4V to 2.4V.
 - Cycle-to-cycle jitter is guaranteed by design.
 - Timing is guaranteed by design and characterization and is not tested.
 - The PLL relock time is the maximum amount of time required for PLL lock after a stable V_{DD} , OV_{DD} , AV_{DD} and SYCLK are reached during the power-on reset sequence. This specification also applies when the PLL has been disabled and subsequently re-enabled during sleep mode. Also note that HRESET must be held asserted for a minimum of 255 bus clocks after the PLL relock time (100 µs) during the power-on reset sequence.
 - Caution:** The SYCLK frequency and PLL_CFG[0-3] settings must be chosen so that the resulting SYCLK (bus) frequency, CPU (core) frequency, and PLL (VCO) frequency do not exceed their respective maximum or minimum operating frequencies. Refer to the PLL_CFG[0-3] signal description for valid PLL_CFG[0-3] settings.

Figure 11-1. SYCLK Input Timing Diagram



11.3.2 Input AC Specifications

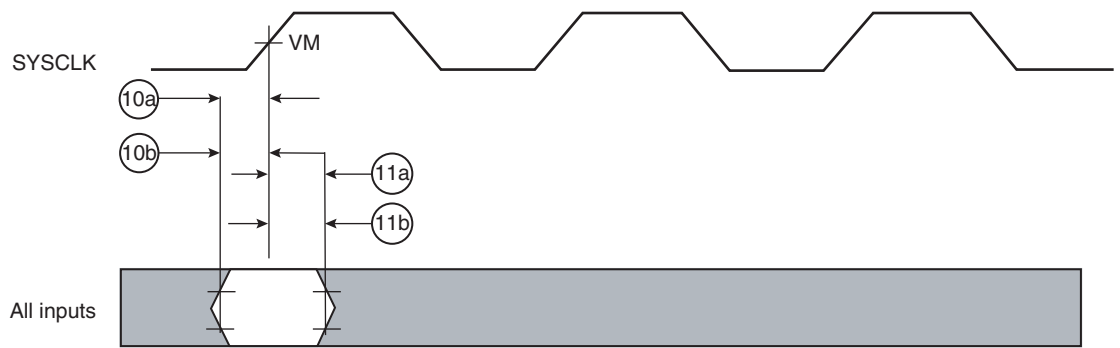
Table 11-3 provides the input AC timing specifications for the 603R as defined in Figure 11-2 and Figure 11-3.

Table 11-3. Input AC Timing Specifications⁽¹⁾ with $V_{DD} = AV_{DD} = 2.5V \pm 5\%$; $OV_{DD} = 3.3 \pm 5\%V$, $GND = 0V$, $-55^{\circ}C \leq T_C \leq 125^{\circ}C$

Figure Number	Characteristics	CBGA 255, HiTCE CBGA 255, CI-CGA 255 and Cerquad 240 Packages		CBGA 255, HiTCE CBGA 255 and CI-CGA 255			Unit	Note	
		166, 200 MHz		233, 266 MHz		300 MHz			
		Min	Max	Min	Max	Min			Max
10a	Address/data/transfer attribute inputs valid to SYSCLK (input setup)	2.5	–	2.5	–	2.5	–	ns	(2)
10b	All other inputs valid to SYSCLK (input setup)	4	–	3.5	–	3.5	–	ns	(3)
10c	Mode select inputs valid to \overline{HRESET} (input setup) (for \overline{DRTRY} , \overline{QACK} and $\overline{TLBISYNC}$)	8	–	8	–	8	–	t_{sysclk}	(4)(5)(6)(7)
11a	SYSCLK to address/data/transfer attribute inputs invalid (input hold)	1	–	1	–	1	–	ns	(2)
11b	SYSCLK to all other inputs invalid (input hold)	1	–	1	–	1	–	ns	(3)
11c	\overline{HRESET} to mode select inputs invalid (input hold) (for \overline{DRTRY} , \overline{QACK} , and $\overline{TLBISYNC}$)	0	–	0	–	0	–	ns	(4)(6)(7)

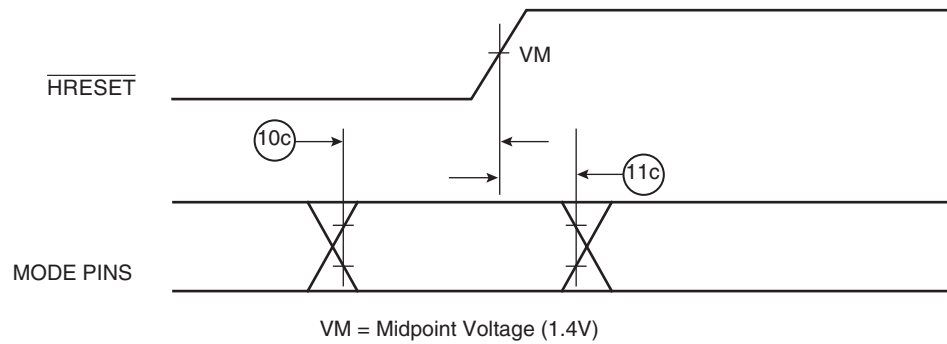
- Notes:
- All input specifications are measured from the TTL level (0.8 or 2V) of the signal in question to the 1.4V of the rising edge of the input SYSCLK. Both input and output timings are measured at the pin. See Figure 11-3.
 - Address/data/transfer attribute input signals are composed of the following: $A[0-31]$, $AP[0-3]$, $TT[0-4]$, $TC[0-1]$, \overline{TBST} , $TSIZ[0-2]$, \overline{GBL} , $DH[0-31]$, $DL[0-31]$, $DP[9-7]$.
 - All other input signals are composed of the following: \overline{TS} , \overline{ABB} , \overline{DBB} , \overline{ARTRY} , \overline{BG} , \overline{AACK} , \overline{DBG} , \overline{DBWO} , \overline{TA} , \overline{DRTRY} , \overline{TEA} , \overline{DBDIS} , \overline{HRESET} , \overline{SRESET} , \overline{INT} , \overline{SMI} , \overline{MCP} , \overline{TBEN} , \overline{QACK} , $\overline{TLBISYNC}$.
 - The setup and hold time is with respect to the rising edge of \overline{HRESET} . See Figure 11-3.
 - t_{sysclk} is the period of the external clock (SYSCLK) in nanoseconds (ns). The numbers given in the table must be multiplied by the period of SYSCLK to compute the actual time duration (in nanoseconds) of the parameter in question.
 - These values are guaranteed by design, and are not tested.
 - This specification is for configuration mode only. Also note that \overline{HRESET} must be held asserted for a minimum of 255 bus clocks after the PLL relock time (100 μs) during the power-on reset sequence.

Figure 11-2. Input Timing Diagram



VM = Midpoint Voltage (1.4V)

Figure 11-3. Mode Select Input Timing Diagram



11.3.3 Output AC Specifications

Table 11-4 provides the output AC timing specifications for the 603R (shown in Figure 11-4).

Table 11-4. Output AC Timing Specifications⁽¹⁾⁽²⁾ with $V_{DD} = AV_{DD} = 2.5V \pm 5\%$; $OV_{DD} = 3.3 \pm 5\%V$, $GND = 0V$, $C_L = 50 pF$, $55^\circ C \leq T_C \leq 125^\circ C$

Number	Characteristics	CBGA 255, HiTCE CBGA 255, CI-CGA 255 and Cerquad 240 Packages		CBGA 255, HiTCE CBGA 255 and CI-CGA 255				Unit	Note
		166, 200 MHz		233, 266 MHz		300 MHz			
		Min	Max	Min	Max	Min	Max		
12	SYSCLK to output driven (output enable time)	1	–	1	–	1	–	ns	
13a	SYSCLK to output valid (5.5V to 0.8V – \overline{TS} , \overline{ABB} , \overline{ARTRY} , \overline{DBB})	–	9	–	9	–	9	ns	(4)
13b	SYSCLK to output valid (\overline{TS} , \overline{ABB} , \overline{ARTRY} , \overline{DBB})	–	8	–	8	–	8	ns	(6)
14a	SYSCLK to output valid (5.5V to 0.8V – all except \overline{TS} , \overline{ABB} , \overline{ARTRY} , \overline{DBB})	–	11	–	11	–	11	ns	(4)
14b	SYSCLK to output valid (all except \overline{TS} , \overline{ABB} , \overline{ARTRY} , \overline{DBB})	–	9	–	9	–	9	ns	(6)
15	SYSCLK to output invalid (output hold)	1	–	1	–	1	–	ns	(3)
16	SYSCLK to output high impedance (all except \overline{ARTRY} , \overline{ABB} , \overline{DBB})	–	8.5	–	8	–	8	ns	
17	SYSCLK to \overline{ABB} , \overline{DBB} , high impedance after precharge	–	1	–	1	–	1	t_{SYSCLK}	(5)(7)
18	SYSCLK to \overline{ARTRY} high impedance before precharge	–	8	–	7.5	–	7.5	ns	
19	SYSCLK to \overline{ARTRY} precharge enable	$0.2 \times t_{SYSCLK} + 1$	–	$0.2 \times t_{SYSCLK} + 1$	–	$0.2 \times t_{SYSCLK}$	–	ns	(3)(5)(8)
20	Maximum delay to \overline{ARTRY} precharge	–	1	–	1	–	1	t_{SYSCLK}	(5)(8)
21	SYSCLK to \overline{ARTRY} high impedance after precharge	–	2	–	2	–	2	t_{SYSCLK}	(6)(8)